Surface Mount PNP General Purpose Transistor



2N2907AUA (TX, TXV)

Features:

- Ceramic 4 pin surface mount package
- Miniature package to minimize circuit board area
- Hermetically sealed
- Processed per MIL-PRF-19500/291



Description:

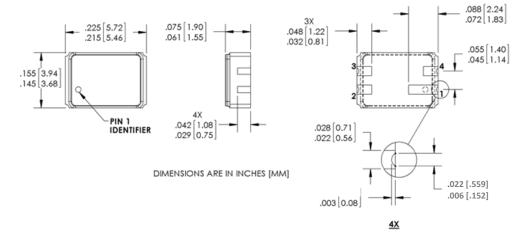
The 2N2907AUA (TX, TXV) is a hermetically sealed ceramic surface mount general purpose switching transistor. The miniature four pin ceramic package is ideal for designs where board space and device weight are important design considerations. The "UA" suffix denotes the 4 terminal leadless chip carrier package, type "A" per MIL-PRF-19500/291.

Typical screening per MIL-PRF-19500/291. The burn-in condition is V_{CB} = 30 V. P_D = 400 mW, T_A = 25° C, t = 80 hrs. Refer to MIL-PRF-19500/291 for complete requirements. In addition, the TX and TXV versions receive 100% thermal response testing.

When ordering parts without processing, do not use the TX or TXV suffix.

Applications:

- General switching
- Amplification
- Signal processing
- Radio transmission
- Logic gates



Pin	Function					
1	Collector					
2	Emitter					
3	Base					
4	No Connection					

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Electrical Specifications

Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Collector-Base Voltage	60 V
Collector-Emitter Voltage	60 V
Emitter-Base Voltage	5.0 V
Collector Current-Continuous	600 mA
Operating Junction Temperature (T _J)	-65° C to +200° C
Storage Junction Temperature (T _{stg})	-65° C to +200° C
Power Dissipation @ T _A = 25° C	0.5 W
Power Dissipation @ Tc = 25° C	1.00 W ⁽¹⁾
Soldering Temperature (vapor phase reflow for 30 seconds)	215° C
Soldering Temperature (heated collet for 5 seconds)	260° C

Electrical Characteristics (T_A = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS	TEST CONDITIONS			
OFF CHARACTERISTICS								
V _{(BR)CBO}	Collector-Base Breakdown Voltage	60		V	I _C = 10 μA, I _E = 0			
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	60		V	I _C = 10 mA, I _B = 0 ⁽²⁾			
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	5.0		V	I _E = 10 μA, I _C = 0			
I _{CBO}	Calleston Boss Cataff Consust		10	μΑ	V _{CB} = 50 V, I _E = 0			
	Collector-Base Cutoff Current		10	μΑ	V _{CB} = 50 V, I _E = 0, T _A = 150° C			
I _{EBO}	Emitter-Base Cutoff Current		10	μΑ	V _{CE} = 4.0 V, I _C = 0			
I _{CES}	Collector Emitter Cutoff Current		50	nA	V _{EB} = 50 V			
ON CHARA	CTERISTICS							
h _{FE}	Forward-Current Transfer Ratio	75		-	V _{CE} = 10 V, I _C = 0.1 mA			
		100	450	-	V _{CE} = 10 V, I _C = 1.0 mA			
		100		-	V _{CE} = 10 V, I _C = 10 mA			
		100	300	-	V _{CE} = 10 V, I _C = 150 mA ⁽²⁾			
		50		-	$V_{CE} = 10 \text{ V, } I_{C} = 500 \text{ mA}^{(2)}$			
		50		-	V _{CE} = 10 V, I _C = 1.0 mA, T _A = -55° C			

Note:

- 1. Derate linearly 6.6 mW/°C above 25° C
- 2. Pulse Width ≤300 μs, Duty Cycle ≤ 2.0%

TT Electronics | OPTEK Technology

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Electrical Specifications

Electrical Characteristics (T_A = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS	TEST CONDITIONS		
OFF CHARACTERISTICS							
V _{CE (SAT)}	Collector-Emitter Saturation Voltage		0.40	V	I _C = 150 mA, I _B = 15 mA ⁽²⁾		
			1.60	V	I _C = 500 mA, I _B = 50 mA ⁽²⁾		
V _{BE(SAT)}	· · · · · · · · · · · · · · · · · ·		1.30	V	I _C = 150 mA, I _B = 15 mA ⁽²⁾		
	Base-Emitter Saturation Voltage		2.60	V	I _C = 500 mA, I _B = 50 mA ⁽²⁾		
SMALL-SIG	NAL CHARACTERISTICS						
h _{fe}	Small Signal Forward Current Transfer Ratio	100		-	V _{CE} = 10 V, I _C = 1.0 mA, f = 1.0 kHz		
h _{fe}	Small Signal Forward Current Transfer Ratio	2.0		-	V _{CE} = 20 V, I _C = 20 mA, f = 100 MHz		
C _{obo}	Open Circuit Output Capacitance		8.0	pF	V _{CB} = 10 V, 100 kHz ≤ f ≤ 1.0 MHZ		
C _{ibo}	Input Capacitance (Output Open)		30	pF	V _{EB} = 2.0 V, 100 kHz ≤ f ≤ 1.0 MHZ		
SWITCHING CHARACTERISTICS							
t _{on}	Turn-On Time		45	ns	V _{CC} = 30 V, I _C = 150 mA, I _{B1} = 15 mA		
t _{off}	Turn-Off Time		300	ns	V _{CC} = 30 V, I _C = 150 mA, I _{B1} = I _{B2} = 15 mA		

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